



VNB14NV04/VND14NV04 VND14NV04-1/VNP14NV04/VNS14NV04

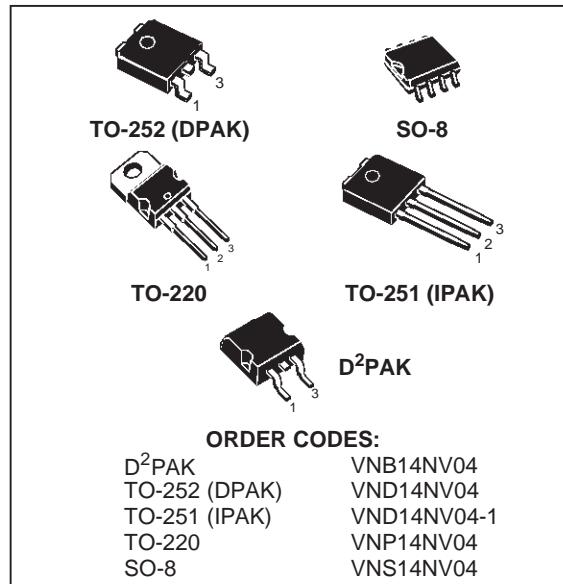
“OMNIFET II”: FULLY AUTOPROTECTED POWER MOSFET

TYPE	R _{DS(on)}	I _{lim}	V _{clamp}
VNB14NV04			
VND14NV04	35 mΩ	12 A	40 V
VND14NV04-1			
VNP14NV04			
VNS14NV04			

- LINEAR CURRENT LIMITATION
- THERMAL SHUT DOWN
- SHORT CIRCUIT PROTECTION
- INTEGRATED CLAMP
- LOW CURRENT DRAWN FROM INPUT PIN
- DIAGNOSTIC FEEDBACK THROUGH INPUT PIN
- ESD PROTECTION
- DIRECT ACCESS TO THE GATE OF THE POWER MOSFET (ANALOG DRIVING)
- COMPATIBLE WITH STANDARD POWER MOSFET

DESCRIPTION

The VNB14NV04, VND14NV04, VND14NV04-1, VNP14NV04, VNS14NV04, are monolithic devices designed in STMicroelectronics VIPower M0-3 Technology, intended for replacement of



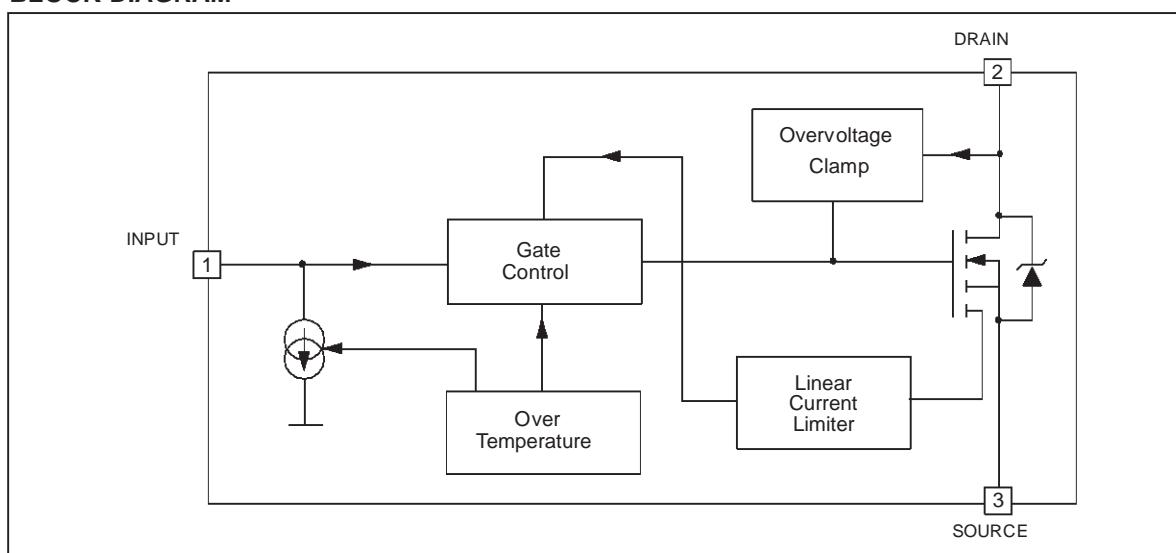
ORDER CODES:

D ² PAK	VNB14NV04
TO-252 (DPAK)	VND14NV04
TO-251 (IPAK)	VND14NV04-1
TO-220	VNP14NV04
SO-8	VNS14NV04

standard Power MOSFETs from DC up to 50KHz applications. Built in thermal shutdown, linear current limitation and overvoltage clamp protect the chip in harsh environments.

Fault feedback can be detected by monitoring the voltage at the input pin.

BLOCK DIAGRAM



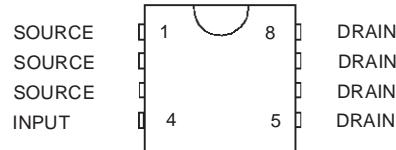
VNB14NV04 / VND14NV04 / VND14NV04-1 / VNP14NV04 / VNS14NV04

ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value					Unit
		SO-8	DPAK	TO-220	IPAK	D ² PAK	
V_{DS}	Drain-source Voltage ($V_{IN}=0V$)			Internally Clamped			V
V_{IN}	Input Voltage			Internally Clamped			V
I_{IN}	Input Current			+/-20			mA
$R_{IN\ MIN}$	Minimum Input Series Impedance			10			Ω
I_D	Drain Current			Internally Limited			A
I_R	Reverse DC Output Current			-15			A
V_{ESD1}	Electrostatic Discharge ($R=1.5K\Omega$, $C=100pF$)			4000			V
V_{ESD2}	Electrostatic Discharge on output pin only ($R=330\Omega$, $C=150pF$)			16500			V
P_{tot}	Total Dissipation at $T_c=25^\circ C$	8.3	50	70	50	70	W
T_j	Operating Junction Temperature			Internally limited			$^\circ C$
T_c	Case Operating Temperature			Internally limited			$^\circ C$
T_{stg}	Storage Temperature			-55 to 150			$^\circ C$

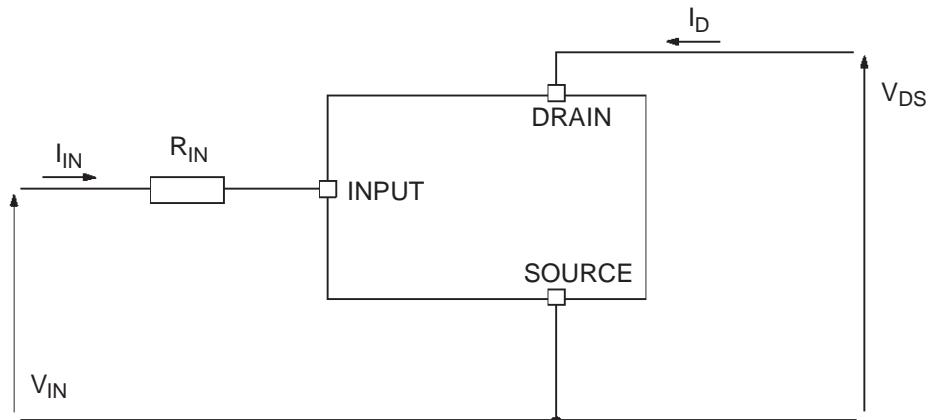
CONNECTION DIAGRAM (TOP VIEW)

SO-8 Package (*)



(*) For the pins configuration related to DPAK, D²PAK, IPAK, TO-220 see outlines at page 1.

CURRENT AND VOLTAGE CONVENTIONS



VNB14NV04 / VND14NV04 / VND14NV04-1 / VNP14NV04 / VNS14NV04

THERMAL DATA

Symbol	Parameter	Value					Unit
		SO-8	DPAK	TO-220	IPIAK	D ² PAK	
R _{thj-case}	Thermal Resistance Junction-case MAX		2.5	1.8	2.5	1.8	°C/W
R _{thj-lead}	Thermal Resistance Junction-lead MAX	15					°C/W
R _{thj-amb}	Thermal Resistance Junction-ambient MAX	65(*)	52.5(*)	50	100	50 (*)	°C/W

(*) When mounted on a standard single-sided FR4 board with 50mm² of Cu (at least 35 µm thick) connected to all DRAIN pins.
Horizontal mounting and no artificial air flow.

ELECTRICAL CHARACTERISTICS (-40°C < T_j < 150°C, unless otherwise specified)

OFF

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V _{CLAMP}	Drain-source Clamp Voltage	V _{IN} =0V; I _D =7A	40	45	55	V
V _{CLTH}	Drain-source Clamp Threshold Voltage	V _{IN} =0V; I _D =2mA	36			V
V _{INTH}	Input Threshold Voltage	V _{DS} =V _{IN} ; I _D =1mA	0.5		2.5	V
I _{ISS}	Supply Current from Input Pin	V _{DS} =0V; V _{IN} =5V		100	150	µA
V _{INCL}	Input-Source Clamp Voltage	I _{IN} =1mA I _{IN} =-1mA	6 -1.0	6.8	8 -0.3	V
I _{DSS}	Zero Input Voltage Drain Current (V _{IN} =0V)	V _{DS} =13V; V _{IN} =0V; T _j =25°C V _{DS} =25V; V _{IN} =0V			30 75	µA

ON

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
R _{DS(on)}	Static Drain-source On Resistance	V _{IN} =5V; I _D =7A; T _j =25°C V _{IN} =5V; I _D =7A			35 70	mΩ

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ELECTRICAL CHARACTERISTICS (continued) ($T_j=25^\circ\text{C}$, unless otherwise specified)

DYNAMIC

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
g_{fs} (*)	Forward Transconductance	$V_{DD}=13\text{V}$; $I_D=7\text{A}$		18		s
C_{OSS}	Output Capacitance	$V_{DS}=13\text{V}$; $f=1\text{MHz}$; $V_{IN}=0\text{V}$		400		pF

SWITCHING

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
$t_{d(on)}$	Turn-on Delay Time	$V_{DD}=15\text{V}$; $I_D=7\text{A}$ $V_{gen}=5\text{V}$; $R_{gen}=R_{IN\ MIN}=10\Omega$ (see figure 1)		80	250	ns
t_r	Rise Time			350	1000	ns
$t_{d(off)}$	Turn-off Delay Time			450	1350	ns
t_f	Fall Time			150	500	ns
$t_{d(on)}$	Turn-on Delay Time	$V_{DD}=15\text{V}$; $I_D=7\text{A}$ $V_{gen}=5\text{V}$; $R_{gen}=2.2\text{K}\Omega$ (see figure 1)		1.5	4.5	μs
t_r	Rise Time			9.7	30.0	μs
$t_{d(off)}$	Turn-off Delay Time			9	25.0	μs
t_f	Fall Time			10.2	30.0	μs
$(di/dt)_{on}$	Turn-on Current Slope	$V_{DD}=15\text{V}$; $I_D=7\text{A}$ $V_{gen}=5\text{V}$; $R_{gen}=R_{IN\ MIN}=10\Omega$		16		$\text{A}/\mu\text{s}$
Q_i	Total Input Charge	$V_{DD}=12\text{V}$; $I_D=7\text{A}$; $V_{IN}=5\text{V}$; $I_{gen}=2.13\text{mA}$ (see figure 5)		36.8		nC

SOURCE DRAIN DIODE

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V_{SD} (*)	Forward On Voltage	$I_{SD}=7\text{A}$; $V_{IN}=0\text{V}$		0.8		V
t_{rr}	Reverse Recovery Time	$I_{SD}=7\text{A}$; $di/dt=40\text{A}/\mu\text{s}$		300		ns
Q_{rr}	Reverse Recovery Charge	$V_{DD}=30\text{V}$; $L=200\mu\text{H}$ (see test circuit, figure 2)		0.8		μC
I_{RRM}	Reverse Recovery Current			5		A

PROTECTIONS (-40°C < T_j < 150°C, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
I_{lim}	Drain Current Limit	$V_{IN}=5\text{V}$; $V_{DS}=13\text{V}$	12	18	24	A
t_{dlim}	Step Response Current Limit	$V_{IN}=5\text{V}$; $V_{DS}=13\text{V}$		45		μs
T_{jsh}	Overtemperature Shutdown		150	175		$^\circ\text{C}$
T_{jrs}	Overtemperature Reset		135			$^\circ\text{C}$
I_{gf}	Fault Sink Current	$V_{IN}=5\text{V}$; $V_{DS}=13\text{V}$; $T_j=T_{jsh}$	10	15	20	mA
E_{as}	Single Pulse Avalanche Energy	starting $T_j=25^\circ\text{C}$; $V_{DD}=24\text{V}$ $V_{IN}=5\text{V}$; $R_{gen}=R_{IN\ MIN}=10\Omega$; $L=24\text{mH}$ (see figures 3 & 4)	400			mJ

(*) Pulsed: Pulse duration = 300μs, duty cycle 1.5%

PROTECTION FEATURES

During normal operation, the INPUT pin is electrically connected to the gate of the internal power MOSFET through a low impedance path.

The device then behaves like a standard power MOSFET and can be used as a switch from DC up to 50KHz. The only difference from the user's standpoint is that a small DC current I_{SS} (typ. 100 μ A) flows into the INPUT pin in order to supply the internal circuitry.

The device integrates:

- OVERVOLTAGE CLAMP PROTECTION:

internally set at 45V, along with the rugged avalanche characteristics of the Power MOSFET stage give this device unrivalled ruggedness and energy handling capability. This feature is mainly important when driving inductive loads.

- LINEAR CURRENT LIMITER CIRCUIT:

limits the drain current I_D to I_{lim} whatever the INPUT pin voltages. When the current limiter is active, the device operates in the linear region, so power dissipation may exceed the capability of the heatsink. Both case and junction temperatures increase, and if this phase lasts long enough, junction temperature may reach the overtemperature threshold T_{jsh} .

- OVERTEMPERATURE AND SHORT CIRCUIT PROTECTION:

these are based on sensing the chip temperature and are not dependent on the input voltage. The location of the sensing element on the chip in the power stage area ensures fast, accurate detection of the junction temperature. Overtemperature cutout occurs in the range 150 to 190 °C, a typical value being 170 °C. The device is automatically restarted when the chip temperature falls of about 15°C below shut-down temperature.

- STATUS FEEDBACK:

in the case of an overtemperature fault condition ($T_j > T_{jsh}$), the device tries to sink a diagnostic current I_{gf} through the INPUT pin in order to indicate fault condition. If driven from a low impedance source, this current may be used in order to warn the control circuit of a device shutdown. If the drive impedance is high enough so that the INPUT pin driver is not able to supply the current I_{gf} , the INPUT pin will fall to 0V. **This will not however affect the device operation: no requirement is put on the current capability of the INPUT pin driver except to be able to supply the normal operation drive current I_{SS} .**

Additional features of this device are ESD protection according to the Human Body model and the ability to be driven from a TTL Logic circuit.

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Figure 1: Switching Time Test Circuit for Resistive Load

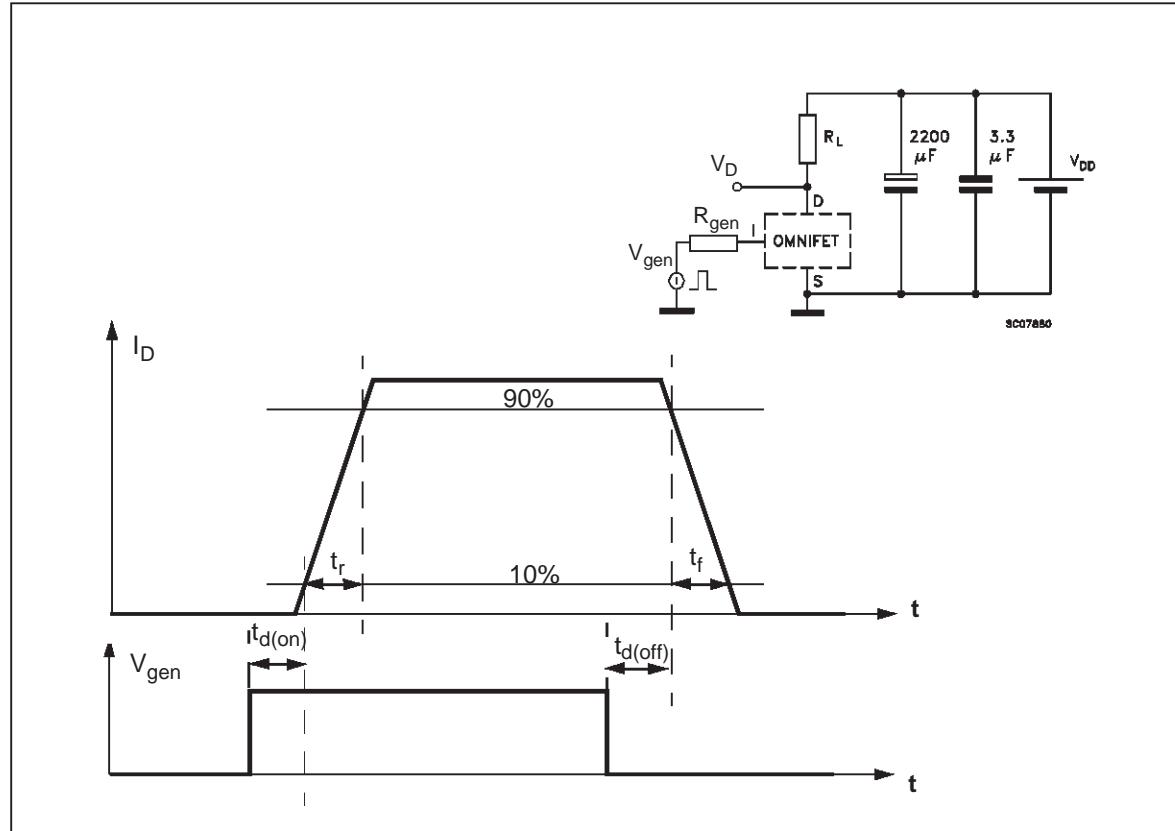
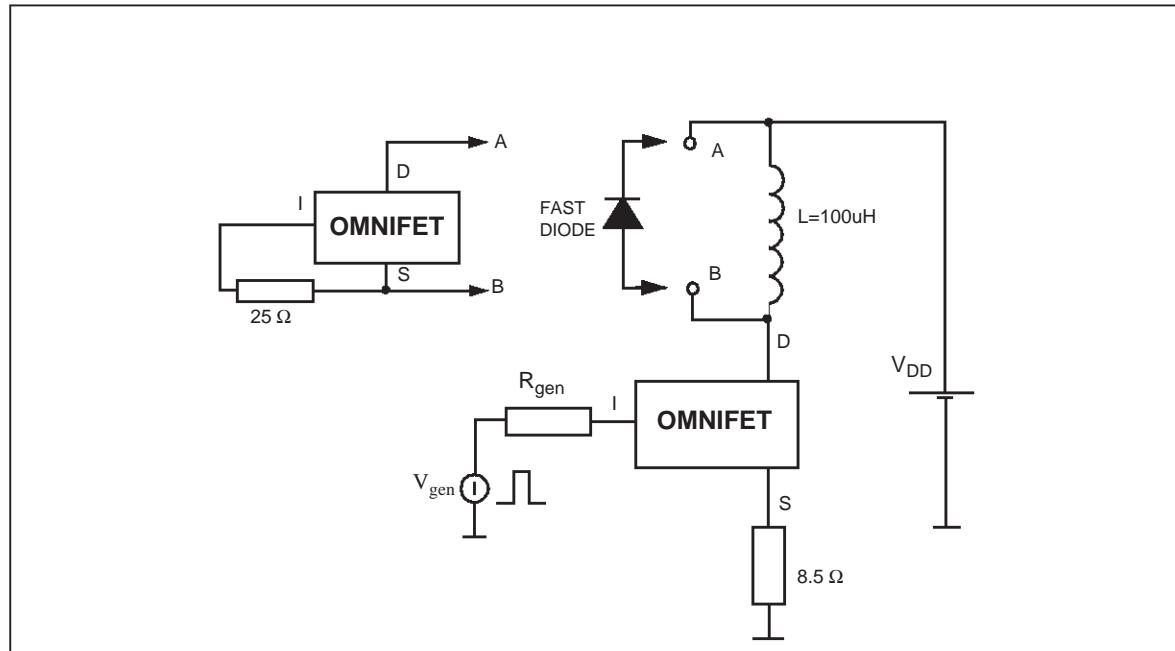


Figure 2: Test Circuit for Diode Recovery Times



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Figure 3: Unclamped Inductive Load Test Circuits

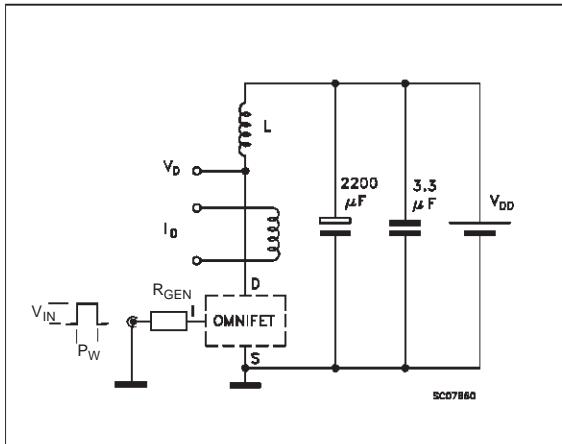


Figure 4: Unclamped Inductive Waveforms

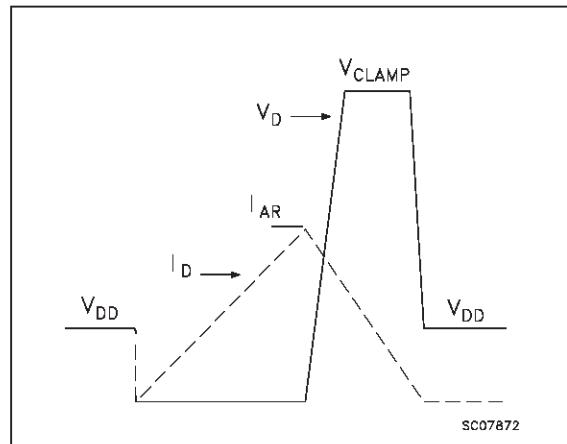
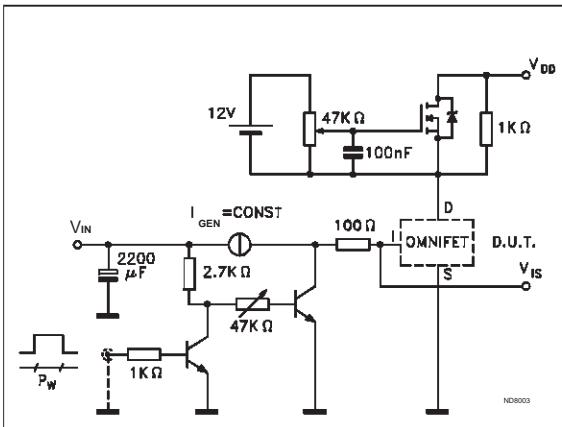
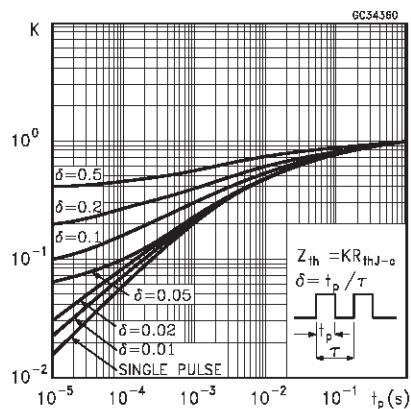


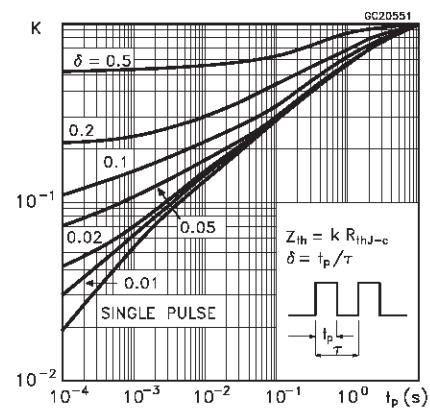
Figure 5: Input Charge Test Circuit



Thermal Impedance for DPAK/IPAK

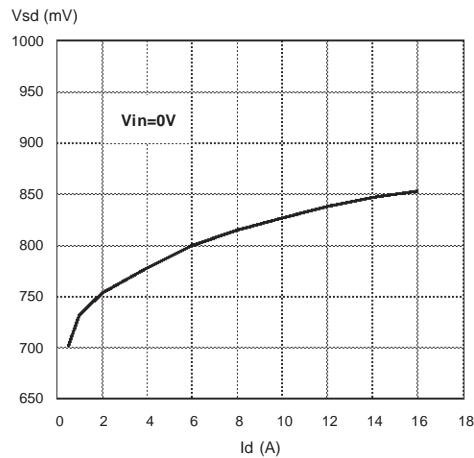


Thermal Impedance for TO-220

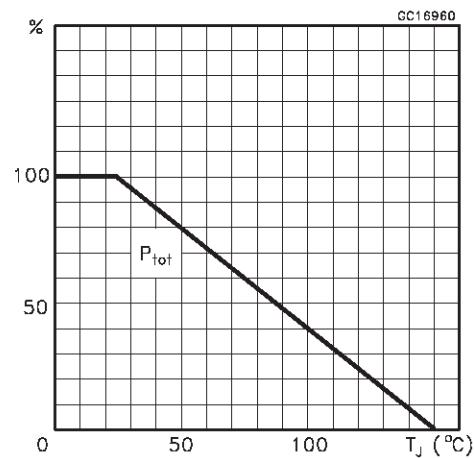


VNB14NV04 / VND14NV04 / VND14NV04-1 / VNP14NV04 / VNS14NV04

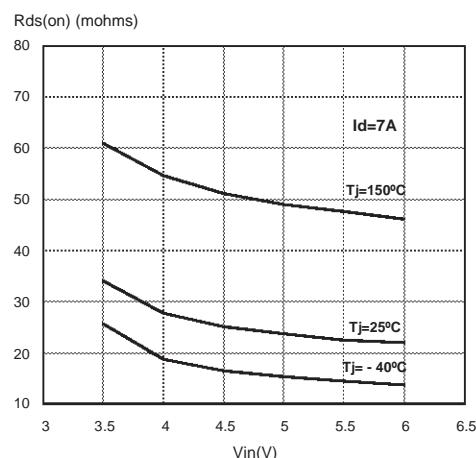
Source-Drain Diode Forward Characteristics



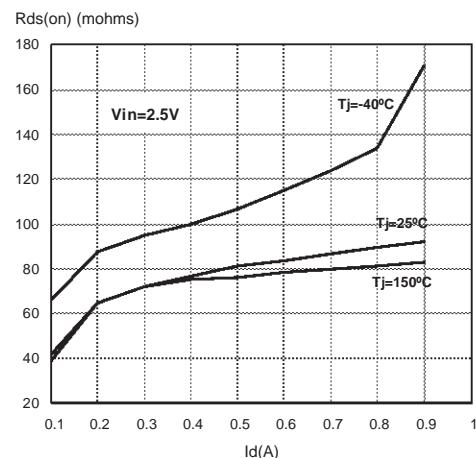
Derating Curve



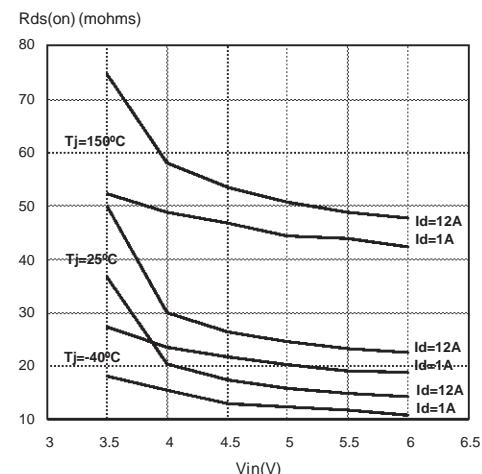
Static Drain-Source On resistance Vs. Input Voltage



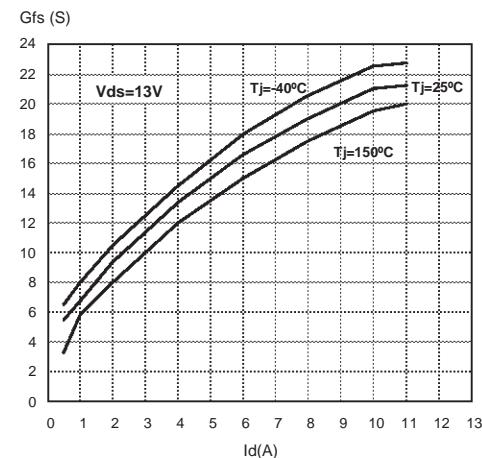
Static Drain Source On Resistance



Static Drain-Source On resistance Vs. Input Voltage

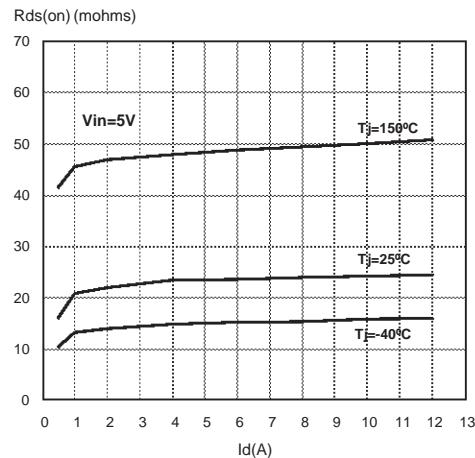


Transconductance

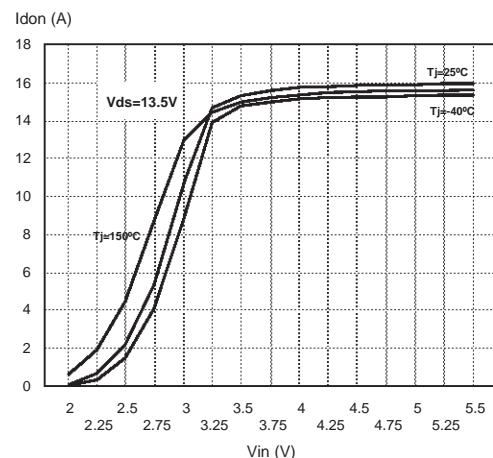


VNB14NV04 / VND14NV04 / VND14NV04-1 / VNP14NV04 / VNS14NV04

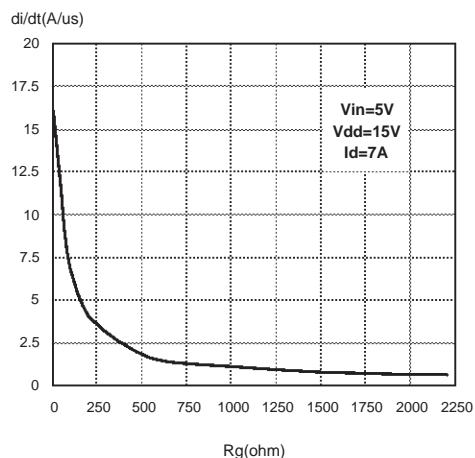
Static Drain-Source On Resistance Vs. Id



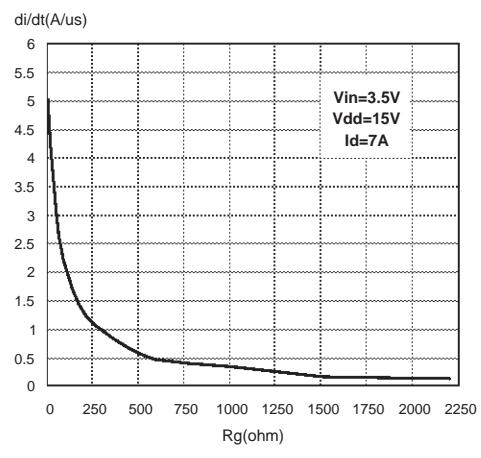
Transfer Characteristics



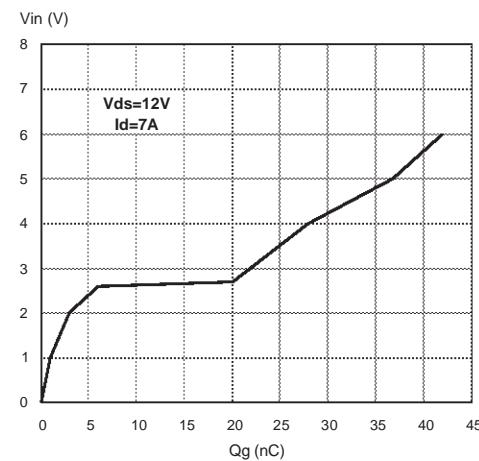
Turn On Current Slope



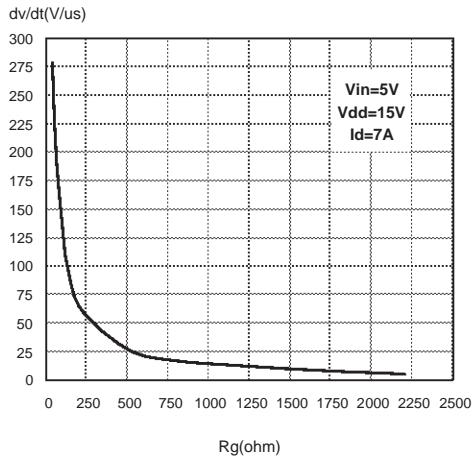
Turn On Current Slope



Input Voltage Vs. Input Charge

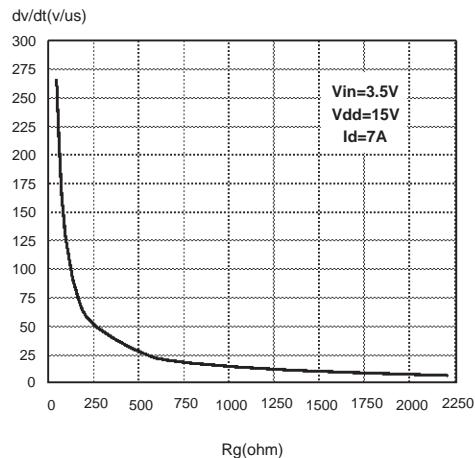


Turn off drain source voltage slope

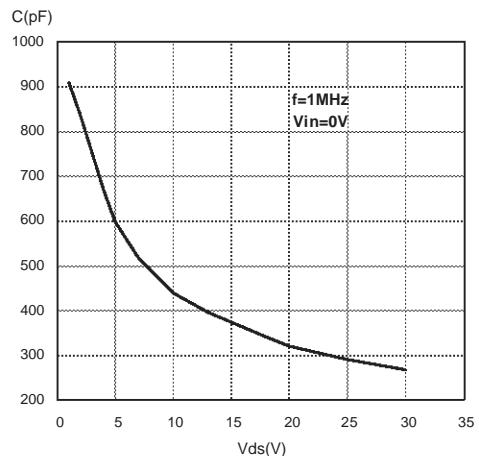


VNB14NV04 / VND14NV04 / VND14NV04-1 / VNP14NV04 / VNS14NV04

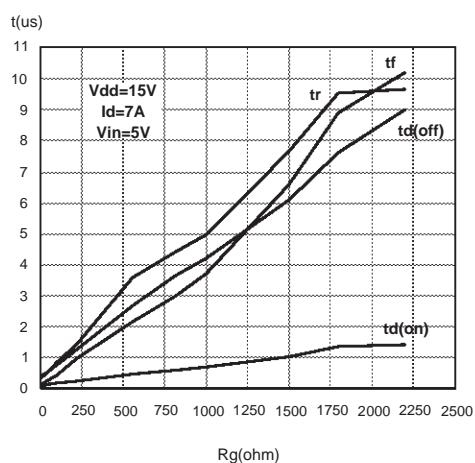
Turn Off Drain-Source Voltage Slope



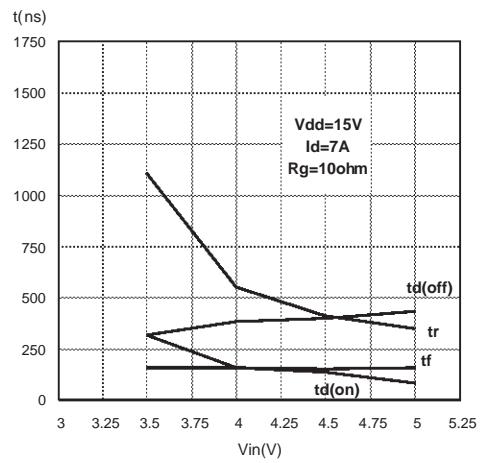
Capacitance Variations



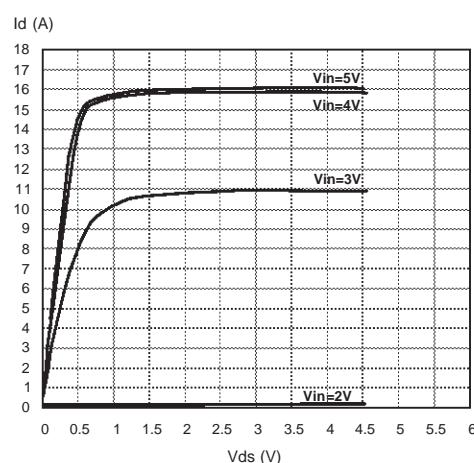
Switching Time Resistive Load



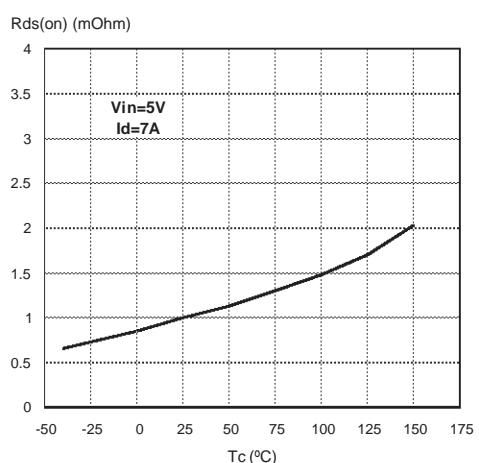
Switching Time Resistive Load



Output Characteristics

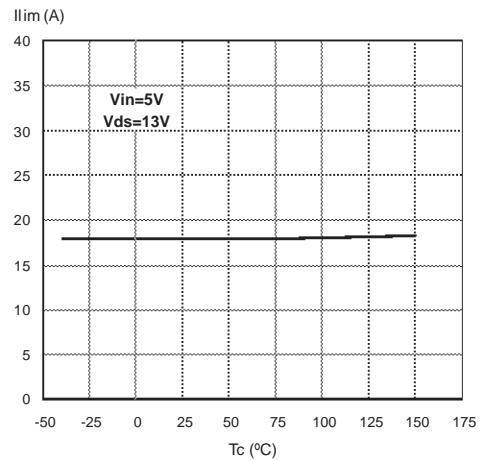
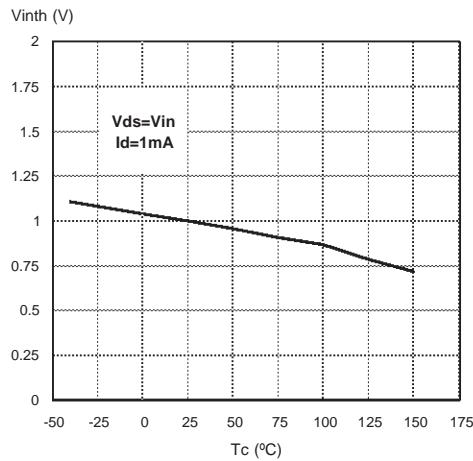


Normalized On Resistance Vs. Temperature

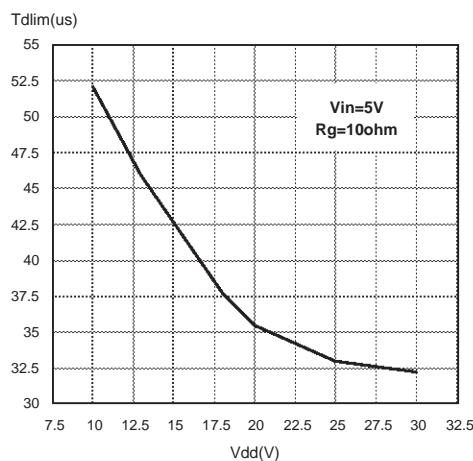


VNB14NV04 / VND14NV04 / VND14NV04-1 / VNP14NV04 / VNS14NV04

Normalized Input Threshold Voltage Vs. Current Limit Vs. Junction Temperature

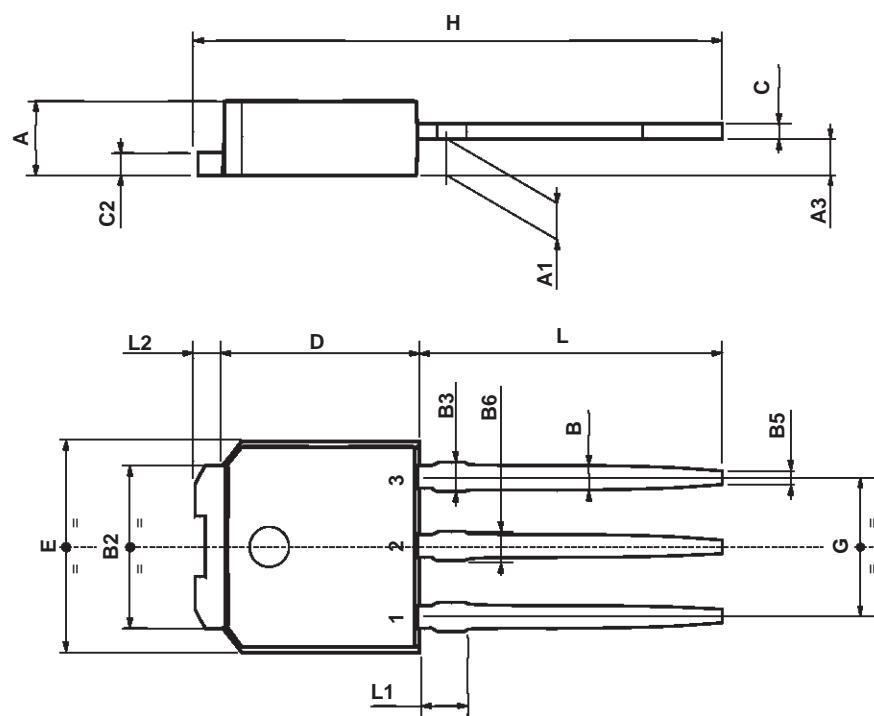


Step Response Current Limit



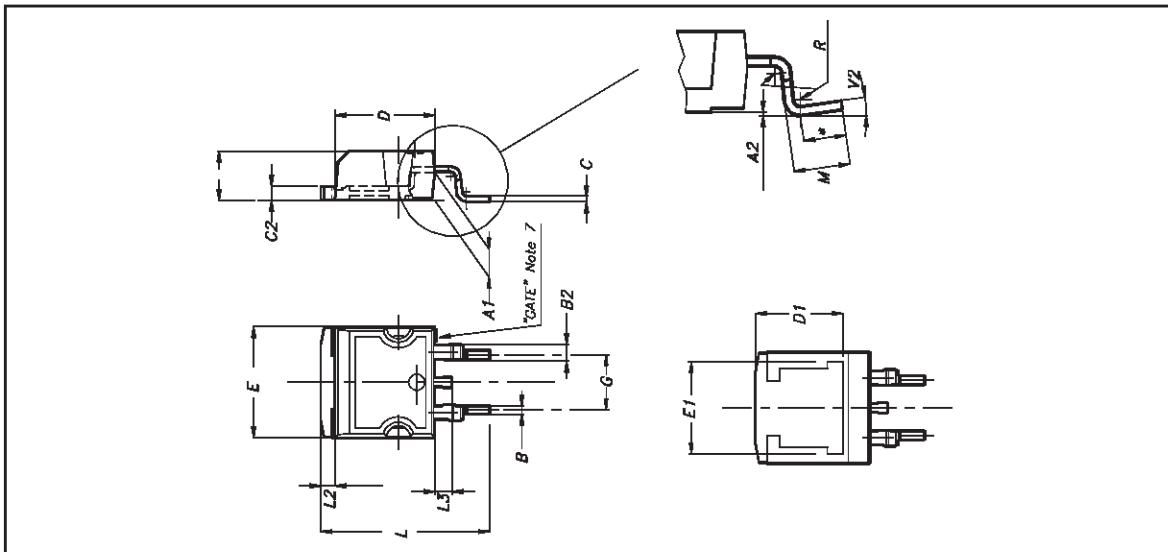
TO-251 (IPAK) MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	2.2		2.4	0.086		0.094
A1	0.9		1.1	0.035		0.043
A3	0.7		1.3	0.027		0.051
B	0.64		0.9	0.025		0.031
B2	5.2		5.4	0.204		0.212
B3			0.85			0.033
B5		0.3			0.012	
B6			0.95			0.037
C	0.45		0.6	0.017		0.023
C2	0.48		0.6	0.019		0.023
D	6		6.2	0.236		0.244
E	6.4		6.6	0.252		0.260
G	4.4		4.6	0.173		0.181
H	15.9		16.3	0.626		0.641
L	9		9.4	0.354		0.370
L1	0.8		1.2	0.031		0.047
L2		0.8	1		0.031	0.039



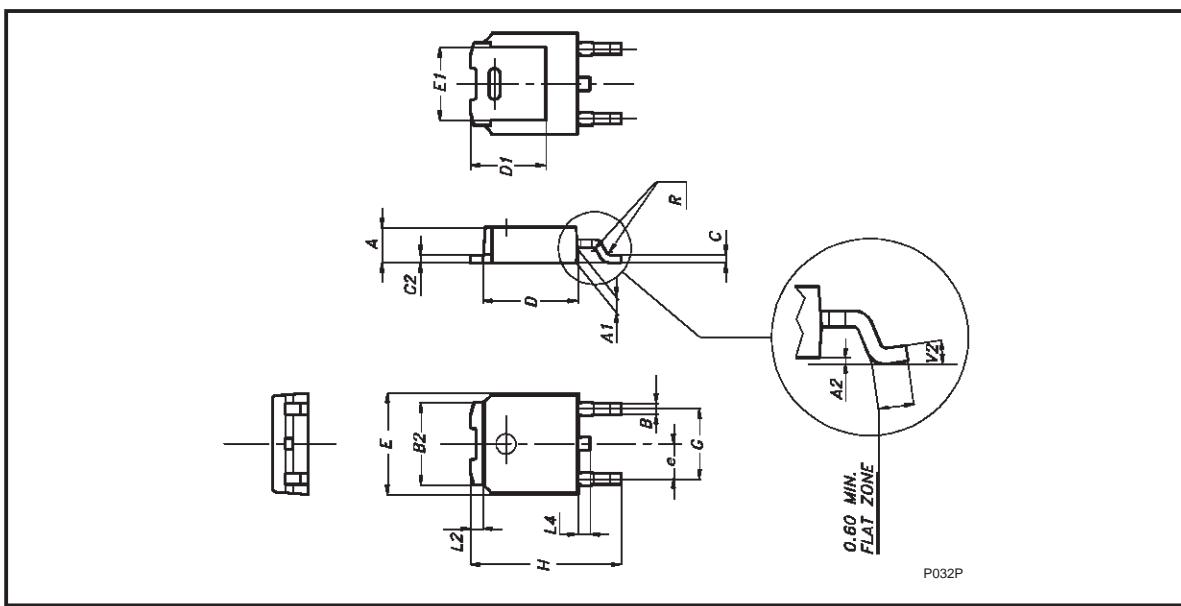
D²PAK MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.4		4.6	0.173		0.181
A1	2.49		2.69	0.098		0.106
A2	0.03		0.23	0.001		0.009
B	0.7		0.93	0.027		0.036
B2	1.14		1.7	0.044		0.067
C	0.45		0.6	0.017		0.023
C2	1.23		1.36	0.048		0.053
D	8.95		9.35	0.352		0.368
D1		8			0.315	
E	10		10.4	0.393		
E1		8.5			0.334	
G	4.88		5.28	0.192		0.208
L	15		15.85	0.590		0.625
L2	1.27		1.4	0.050		0.055
L3	1.4		1.75	0.055		0.069
M	2.4		3.2	0.094		0.126
R		0.4			0.015	
V2	0°		8°			



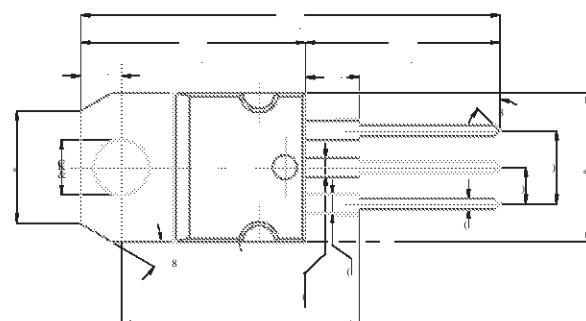
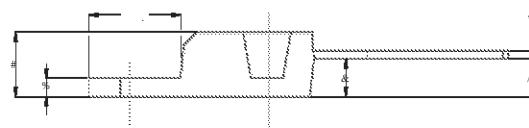
TO-252 (DPAK) MECHANICAL DATA

DIM.	mm.		
	MIN.	TYP	MAX.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
B	0.64		0.90
B2	5.20		5.40
C	0.45		0.60
C2	0.48		0.60
D	6.00		6.20
D1		5.1	
E	6.40		6.60
E1		4.7	
e		2.28	
G	4.40		4.60
H	9.35		10.10
L2		0.8	
L4	0.60		1.00
R		0.2	
V2	0°	8°	
Package Weight	Gr. 0.29		



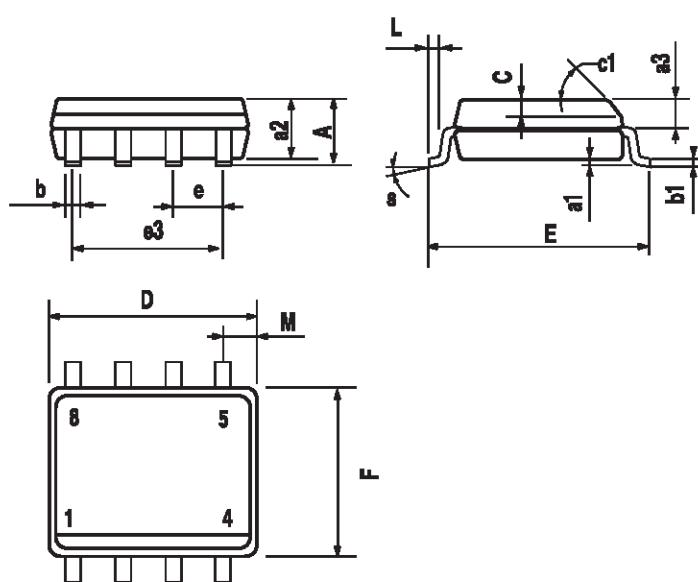
TO-220 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	4.40		4.60	0.173		0.181
C	1.23		1.32	0.048		0.051
D	2.40		2.72	0.094		0.107
E	0.49		0.70	0.019		0.027
F	0.61		0.88	0.024		0.034
F1	1.14		1.70	0.044		0.067
F2	1.14		1.70	0.044		0.067
G	4.95		5.15	0.194		0.203
G1	2.4		2.7	0.094		0.106
H2	10.0		10.40	0.393		0.409
L2		16.4			0.645	
L4	13.0		14.0	0.511		0.551
L5	2.65		2.95	0.104		0.116
L6	15.25		15.75	0.600		0.620
L7	6.2		6.6	0.244		0.260
L9	3.5		3.93	0.137	0.154	
M		2.6			0.102	
DIA.	3.75		3.85	0.147		0.151



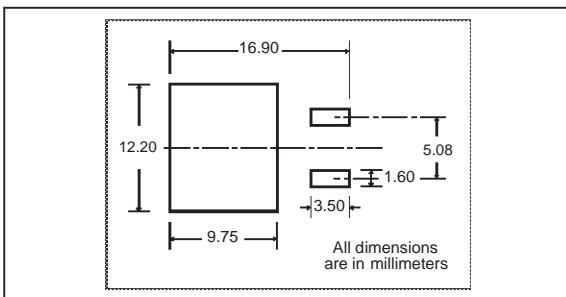
SO-8 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.25	0.003		0.009
a2			1.65			0.064
a3	0.65		0.85	0.025		0.033
b	0.35		0.48	0.013		0.018
b1	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.019
c1	45 (typ.)					
D	4.8		5.0	0.188		0.196
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		3.81			0.150	
F	3.8		4.0	0.14		0.157
L	0.4		1.27	0.015		0.050
M			0.6			0.023
F	8 (max.)					



VNB14NV04 / VND14NV04 / VND14NV04-1 / VNP14NV04 / VNS14NV04

D²PAK FOOTPRINT

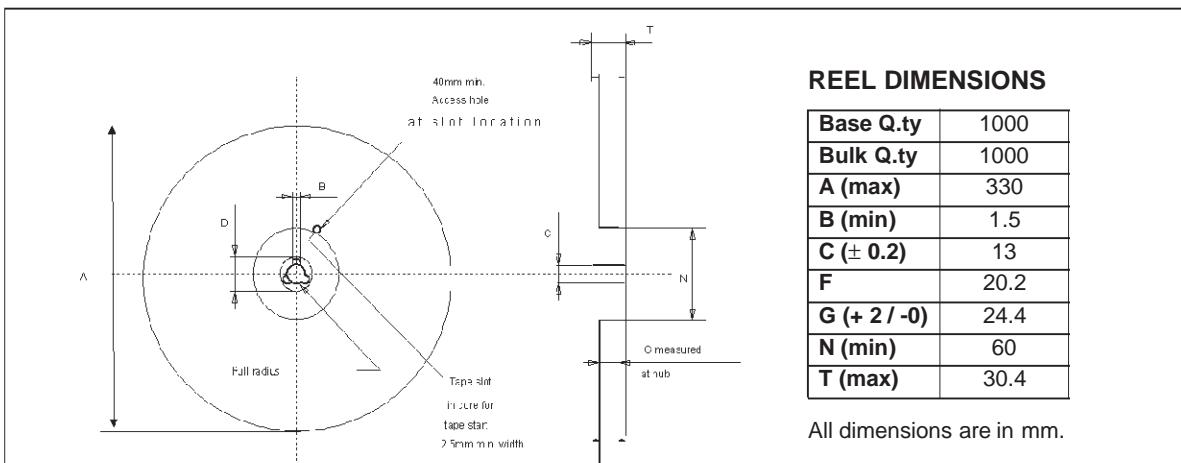


TUBE SHIPMENT (no suffix)

Base Q.ty	50
Bulk Q.ty	500
Tube length (± 0.5)	532
A	6
B	21.3
C (± 0.1)	0.6

All dimensions are in mm.

TAPE AND REEL SHIPMENT (suffix "13TR")

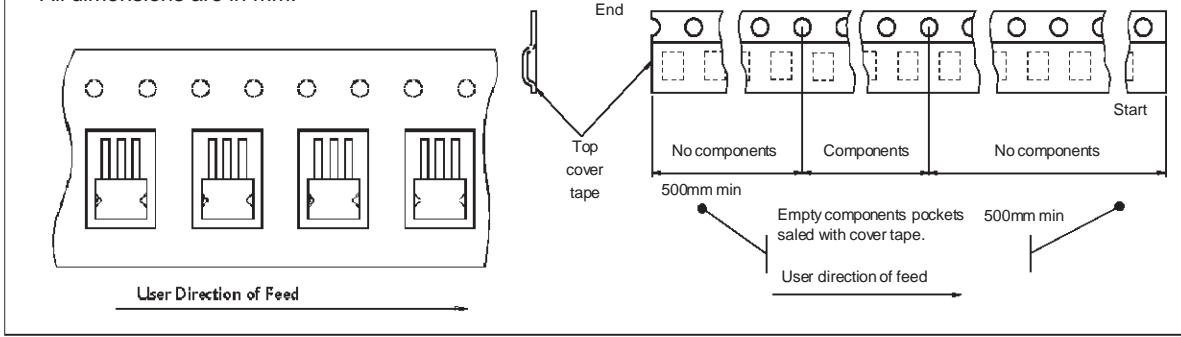
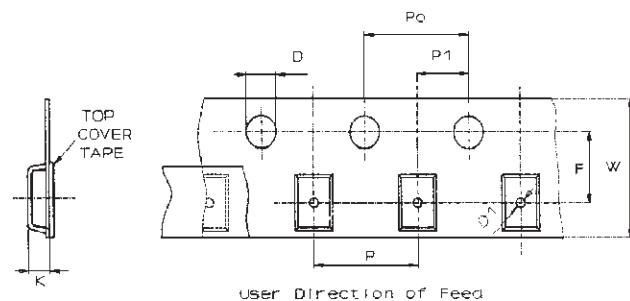


TAPE DIMENSIONS

According to Electronic Industries Association (EIA) Standard 481 rev. A, Feb 1986

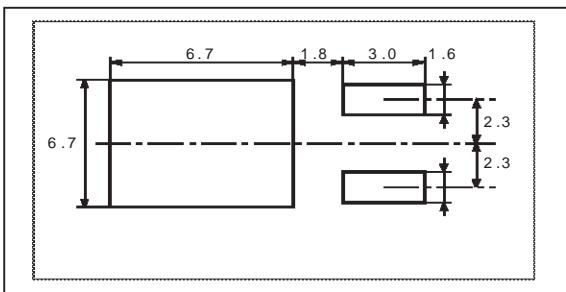
Tape width	W	24
Tape Hole Spacing	P0 (± 0.1)	4
Component Spacing	P	16
Hole Diameter	D ($\pm 0.1/-0$)	1.5
Hole Diameter	D1 (min)	1.5
Hole Position	F (± 0.05)	11.5
Compartment Depth	K (max)	6.5
Hole Spacing	P1 (± 0.1)	2

All dimensions are in mm.



VNB14NV04 / VND14NV04 / VND14NV04-1 / VNP14NV04 / VNS14NV04

DPAK FOOTPRINT

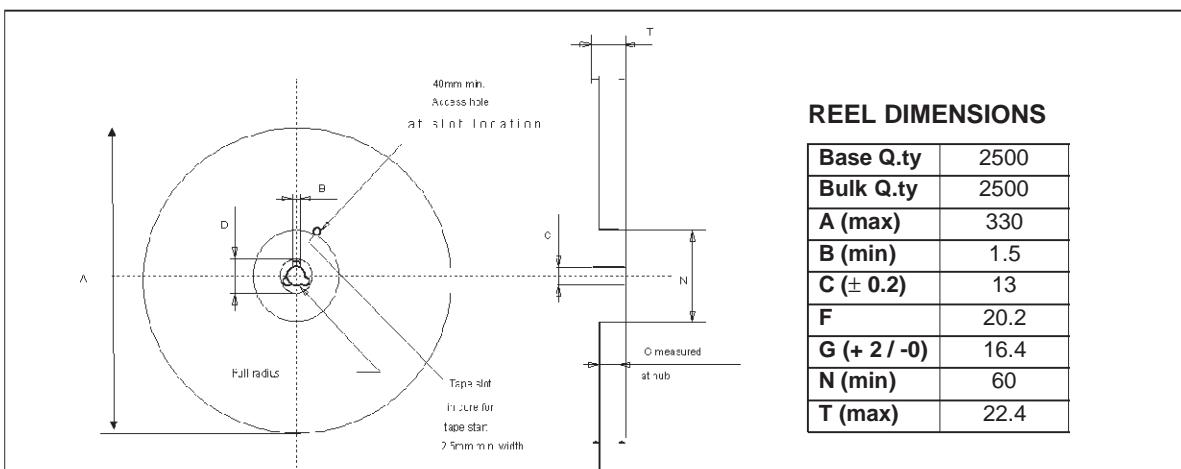


TUBE SHIPMENT (no suffix)

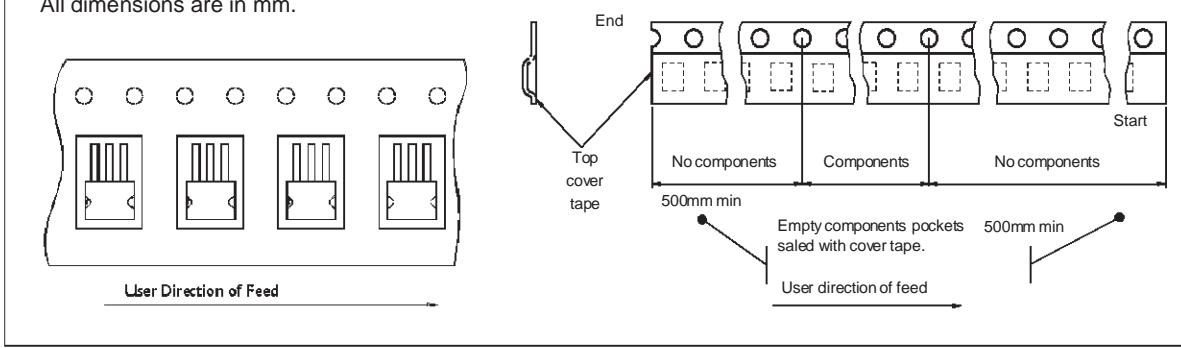
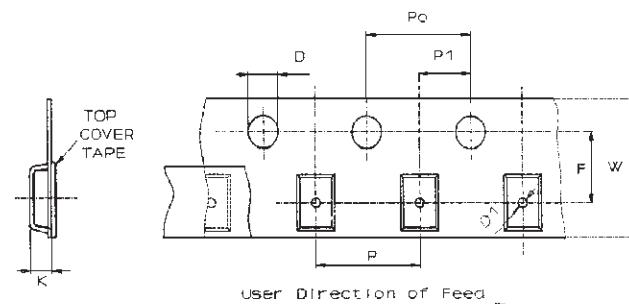
Base Q.ty	75
Bulk Q.ty	3000
Tube length (± 0.5)	532
A	6
B	21.3
C (± 0.1)	0.6

All dimensions are in mm.

TAPE AND REEL SHIPMENT (suffix "13TR")

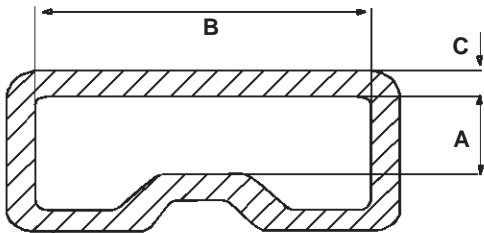


All dimensions are in mm.



VNB14NV04 / VND14NV04 / VND14NV04-1 / VNP14NV04 / VNS14NV04

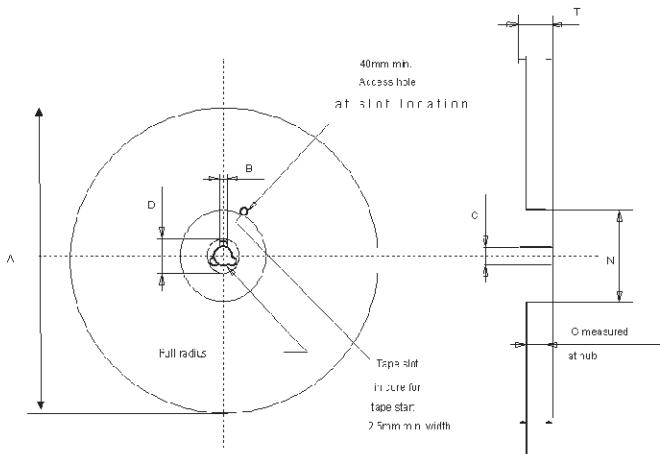
SO-8 TUBE SHIPMENT (no suffix)



Base Q.ty	100
Bulk Q.ty	2000
Tube length (± 0.5)	532
A	3.2
B	6
C (± 0.1)	0.6

All dimensions are in mm.

TAPE AND REEL SHIPMENT (suffix "13TR")



REEL DIMENSIONS

Base Q.ty	2500
Bulk Q.ty	2500
A (max)	330
B (min)	1.5
C (± 0.2)	13
F	20.2
G ($+2/-0$)	12.4
N (min)	60
T (max)	18.4

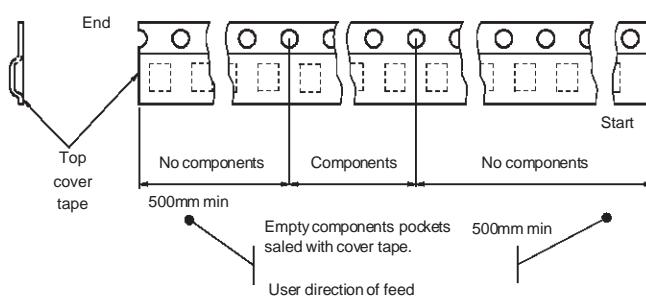
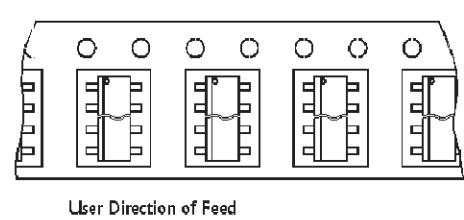
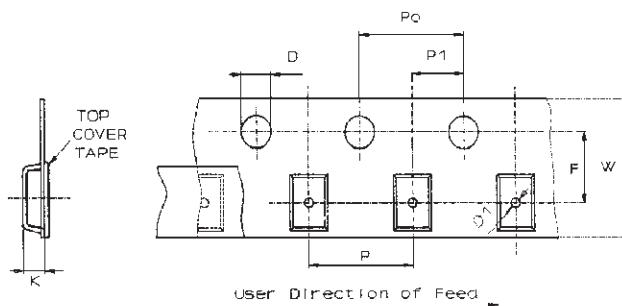
All dimensions are in mm.

TAPE DIMENSIONS

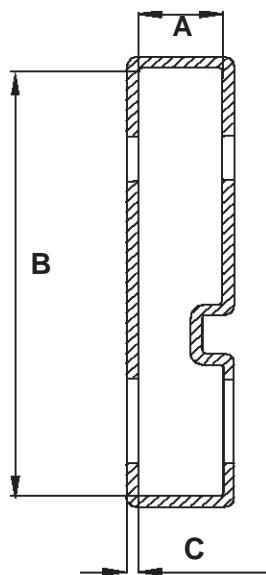
According to Electronic Industries Association (EIA) Standard 481 rev. A, Feb 1986

Tape width	W	12
Tape Hole Spacing	P0 (± 0.1)	4
Component Spacing	P	8
Hole Diameter	D ($\pm 0.1/-0$)	1.5
Hole Diameter	D1 (min)	1.5
Hole Position	F (± 0.05)	5.5
Compartment Depth	K (max)	4.5
Hole Spacing	P1 (± 0.1)	2

All dimensions are in mm.



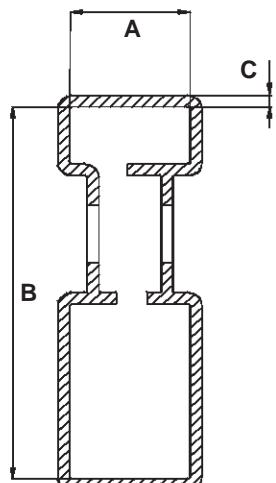
TO-220 TUBE SHIPMENT (no suffix)



Base Q.ty	50
Bulk Q.ty	1000
Tube length (± 0.5)	532
A	5.5
B	31.4
C (± 0.1)	0.75

All dimensions are in mm.

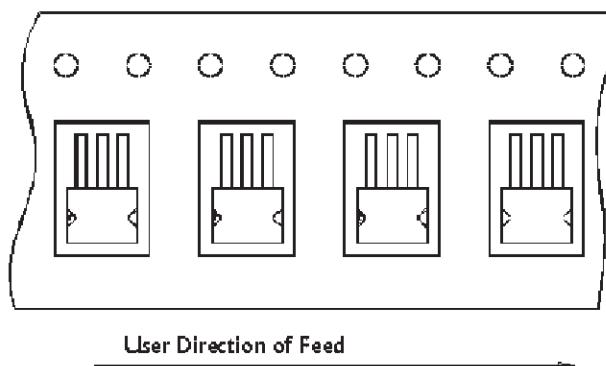
IPAK TUBE SHIPMENT (no suffix)



Base Q.ty	75
Bulk Q.ty	3000
Tube length (± 0.5)	532
A	6
B	21.3
C (± 0.1)	0.6

All dimensions are in mm.

MECHANICAL POLARIZATION



VNB14NV04 / VND14NV04 / VND14NV04-1 / VNP14NV04 / VNS14NV04

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